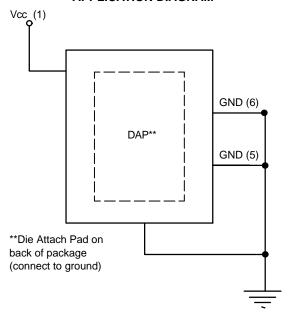
15 V and 18 V Unidirectional Transient Voltage Suppressors

Features

- Unidirectional High Voltage ESD Protection
- Provides ESD Protection to IEC61000-4-2 Level 4: ±30 kV Contact Discharge
- IEC 61000-4-5 (lighting)
- High Voltage Zener Diode Protects Supply Rail up to 100 A (8/20 μs)
- These Devices are Pb-Free and are RoHS Compliant

APPLICATION DIAGRAM





ON Semiconductor®

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UDFN-6 D4 SUFFIX CASE 517CS

BLOCK DIAGRAM



MARKING DIAGRAM



Ax = Specific Device Code

x = 5 or 8

M = Date Code■ = Pb-Free Package

ORDERING INFORMATION

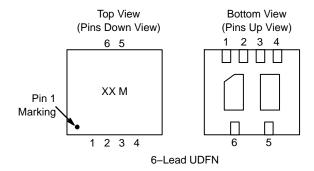
Device	Package	Shipping [†]
TVS8151MUTBG	UDFN-6 (Pb-Free)	3000/Tape & Reel
TVS8181MUTBG	UDFN-6 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Table 1. PIN DESCRIPTIONS

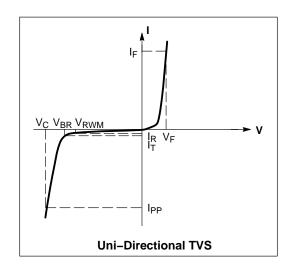
	4-Channel, 6-Lead, UDFN-8 Package					
Pin	Name	Туре	Description			
1	V _{CC}	HV V _{DD}	HV ESD Channel			
2	N/C		No Connect			
3	N/C		No Connect			
4	N/C		No Connect			
5	GND		Ground			
6	GND		Ground			

PACKAGE / PINOUT DIAGRAMS



ELECTRICAL CHARACTERISTICS

Symbol	Parameter				
I _{PP}	Maximum Reverse Peak Pulse Current				
V _C	Clamping Voltage @ IPP				
V_{RWM}	Working Peak Reverse Voltage				
I _R	Maximum Reverse Leakage Current @ V _{RWM}				
V _{BR}	Breakdown Voltage @ I _T				
I _T	Test Current				
ΘV_{BR}	Maximum Temperature Coefficient of V _{BR}				
I _F	Forward Current				
V _F	Forward Voltage @ I _F				



SPECIFICATIONS

Table 2. ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Units
Operating Temperature Range	-55 to +125	°C
Storage Temperature Range	-65 to +150	°C
Peak Current ($t_p = 8/20 \mu s$) TVS8151	100	Α
Peak Current ($t_p = 8/20 \mu s$) TVS8181	119	Α

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS

		V _{RWM} (V)		Breakdown Volta		tage	V _C @ I _{PP} (8 x 20 μs) (Note 3)		
	Device	(Note 1)	I _R @ V _{RWM} (μΑ)	V _B	V _{BR} V (Note 2)		@ I _T (mA)	V _C (V)	I _{PP} (A)
Device Name	Marking	Max	Max	Min	Nom	Max		Max	
TVS8151	A5	15	1	16	17.5	18.5	1	27	100
TVS8181	A8	18	1	20	22.5	23.5	1	28 30	70 100

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 1. A transient suppressor is normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal to or greater than the DC or continuous peak operating voltage level.
- 2. V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C.
- 3. Surge current waveform per Figure 1.

TYPICAL CHARACTERISTICS

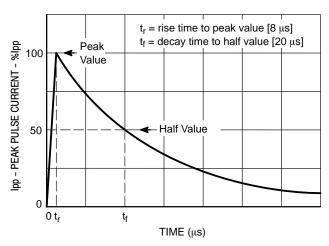
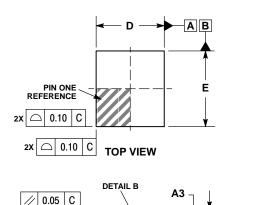


Figure 1. IEC61000-4-5 8/20 μs Pulse Waveform

PACKAGE DIMENSIONS

UDFN6, 1.8x2, 0.4P CASE 517CS **ISSUE O**

EXPOSED Cu

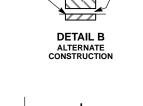


SIDE VIEW

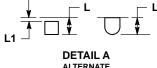
6X

 \Box 0.05 С

NOTE 4



MOLD CMPD



MIN MAX 0.45 0.55 Α A1 0.00 0.05 **A3** 0.125 REF b 0.15 0.25 1.80 BSC 0.35 0.55 D D2 2.00 BSC E2 0.74 0.94 0.40 BSC **e**1 0.80 BSC

0.20

0.95 BSC

0.15

FROM THE TERMINAL TIP.

AS WELL AS THE TERMINALS **MILLIMETERS**

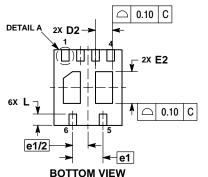
DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS. DIMENSION 6 APPLIES TO PLATED TERMINALS AND IS MEASURED BETWEEN 0.15 AND 0.30mm

COPLANARITY APPLIES TO THE EXPOSED PAD

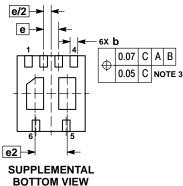
NOTES



C SEATING PLANE

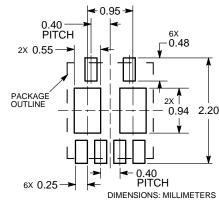


A1





e2



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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ESD119B1W01005E6327XTSA1 ESD5V0J4-TP ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF
3.0SMCJ33CA-F 3.0SMCJ36A-F HSPC16701B02TP D3V3Q1B2DLP3-7 D55V0M1B2WS-7 DESD5V0U1BL-7B DRTR5V0U4SL-7
SCM1293A-04SO ESD200-B1-CSP0201 E6327 ESD203-B1-02EL E6327 SM12-7 SMF8.0A-TP SMLJ45CA-TP CEN955 W/DATA
82350120560 82356240030 VESD12A1A-HD1-GS08 CPDUR5V0R-HF CPDUR24V-HF CPDQC5V0U-HF CPDQC5V0USP-HF
CPDQC5V0-HF D1213A-01LP4-7B D1213A-02WL-7 ESDLIN1524BJ-HQ 5KP100A